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# TX75XXH series 150mA Low Power LDO

### Features

- Quiescent Current: 4.2uA@12V
- PSRR:60dB@100Hz
- Voltage drop:600mV@100mA
- ESD HBM:8KV

### Applications

- Battery-powered equipment
- Communication equipment

- High input voltage (up to 40V)
- Output voltage accuracy: tolerance  $\pm 2\%$
- Output current:150mA(Typ.)

• TO92,SOT89,SOT89B,SOT23-3,SOT23-5 and SOT23-5B package

Audio/Video equipment

## **General Description**

The TX75XXH series is a set of three-terminal low power high voltage regulators implemented in CMOS technology. They allow input voltages as high as 40V. They are available with several fixed output voltages ranging from 1.8V to 5.0V. CMOS technology ensures low voltage drop and low quiescent current. Although designed primarily as fixed voltage regulators, these devices can be used with external components to obtain variable voltages and currents.

## **Selection Table**

Part No.	Output Voltage	Package	Marking
TX7518Hxx	1.8V		
TX7525Hxx	2.5V	TO92	75XX-H#(for TO92)
TX7527Hxx	2.7V	SOT89	· · · · · ·
TX7530Hxx	3.0V	SOT89B	75XX-H#(for SOT89)
TX7533Hxx	3.3V	~	75XX-BH#(for SOT89B)
TX7536Hxx	3.6V	SOT23-3	XXH(for SOT23-5&SOT23-3)
TX7540Hxx	4.0V	SOT23-5	XXBH(for SOT23-5B)
TX7544Hxx	4.4V	SOT23-5B	AADII(101 SO125-3D)
TX7550Hxx	5.0V		

Note:"XX" stands for output voltages.

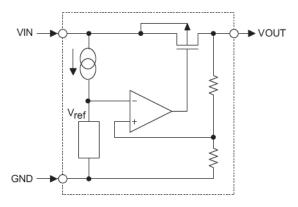
TO92 & SOT89 packages will add a "#" mark at the end of the marking.

### **Order Information**

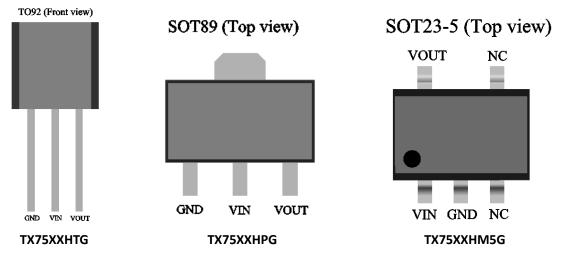
TX7512345

Designator	Symbol	Description
12	Integer	Output Voltage(1.8~5.0V)
3	Н	Standard
4	Т	Package:TO-92
	Р	Package:SOT89
	PB	Package:SOT89B
	М	Package:SOT23-3
	M5	Package:SOT23-5
	M5B	Package:SOT23-5B
5	G	Halogen Free

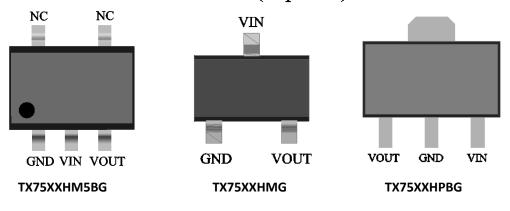
## **Block Diagram**







SOT23-5B (Top view) SOT23-3 (Top view) SOT89B (Top view)



### **Absolute Maximum Ratings**

Supply Voltage .....-0.3V to 40V Operating Temperature .....-40°C to 125°C Storage Temperature ......50℃ to 125℃

Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

### **Thermal Information**

Symbol	Parameter	Package	Max.	Unit
		TO92	200	°C/W
0	Thermal Resistance (Junction to	SOT89	200	°C/W
<sup>Ө</sup> ЈА	<ul> <li>θ JA Ambient) (Assume no ambient airflow, no heat sink)</li> </ul>	SOT23-3	500	°C/W
		SOT23-5	500	°C/W
	P <sub>D</sub> Power Dissipation	TO92	0.50	W
Р		SOT89	0.50	W
PD		SOT23-3	0.20	W
		SOT23-5	0.20	W

Note:  $P_D$  is measured at Ta= 25 °C

## **Electrical Characteristics**

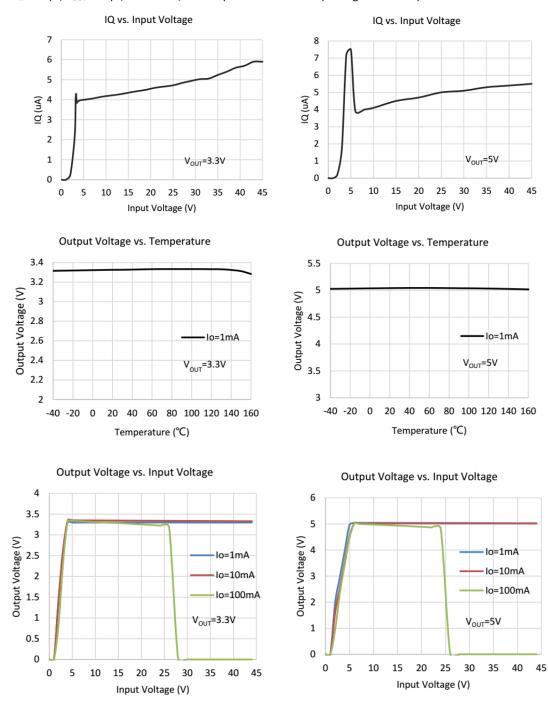
The following specifications apply for VIN = 12V, TA=25  $^\circ C$  ,  $C_{IN}=C_{OUT}=10 \mu F$ , unless specified otherwise.

SYMBOL	ITEMS	CONDITIONS		MIN	ТҮР	МАХ	UNIT
V <sub>IN</sub>	Input Range	I <sub>OUT</sub> = 30mA		V <sub>OUT</sub> +0.3		40	V
V <sub>OUT</sub>	Output Range	I <sub>OUT</sub> = 10mA		V <sub>OUT</sub> x0.98	V <sub>OUT</sub>	V <sub>OUT</sub> x1.02	v
				4.9	5	5.1	
4.57	Output Voltage	V <sub>IN</sub> = 12V, I <sub>OUT</sub> = 10mA		3.234	3.3	3.366	v
∆V <sub>OUT</sub>				2.94	3.0	3.06	
		V <sub>IN</sub> = 7V, I <sub>OUT</sub> = 0			4	6	
Ι <sub>Q</sub>	Quiescent Current	V <sub>IN</sub> = 24V, I <sub>OUT</sub> = 0			4.6	6.7	μΑ
		V <sub>IN</sub> = 40V, I <sub>OUT</sub> = 0			5.4	8.2	
I <sub>OUT_PK</sub>	Maximum Output Current	V <sub>IN</sub> = 12V, R <sub>L</sub> =1Ω			190		mA
		I <sub>OUT</sub> = 1mA			200	300	
V <sub>DROP</sub>	Dropout Voltage	I <sub>OUT</sub> = 100mA			600	900	mV
		V <sub>IN</sub> =7 ~ 24V, V <sub>OUT</sub> = 5V, I <sub>OUT</sub> =	= 1mA		0.02	0.03	
$\Delta V_{\text{LINE}}$	Line Regulation	V <sub>IN</sub> = 7 ~ 45V, V <sub>OUT</sub> = 5V, I <sub>OUT</sub> =	= 1mA		0.08	0.1	%/V
$\bigtriangleup V_{\text{LOAD}}$	Load Regulation	V <sub>IN</sub> = 7V , I <sub>OUT</sub> = 1 ~ 100mA			19	37	mV
I <sub>SHORT</sub>	Short Current	$V_{OUT}$ Short to GND with 1 $\Omega$ (1ms pulse), $V_{IN}$ = 40V			180		mA
		V <sub>IN</sub> = 10V,	F = 100Hz		60		
PSRR	Power Supply Rejection	V <sub>PP</sub> = 0.5V,	F = 1kHz		50		dB
	Rate	I <sub>OUT</sub> = 1mA F = 10kHz			40		
e <sub>NO</sub>	Output Noise Voltage	10Hz to 100kHz, C <sub>OUT</sub> = 10 μF, I <sub>OUT</sub> =10mA			±100		$\mu V_{RMS}$
T <sub>SD</sub>	Thermal Shutdown Protection	V <sub>IN</sub> = 12V, I <sub>OUT</sub> = 1mA			165		°C
ΔV <sub>0</sub> /ΔΤ	Temperature Coefficient				±0.5		mV <b>/</b> ℃

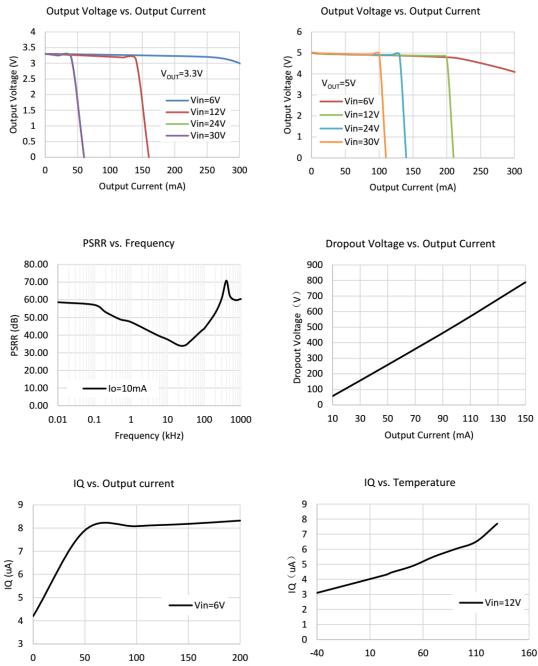
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# TX75XXH series 150mA Low Power LDO

### **Typical Performance Characteristics**



 $C_{IN}$  = 10µF,  $C_{OUT}$  = 10µF,  $T_{OPT}$  = 25°C, unless specified otherwise. (Package: SOT89-3L)

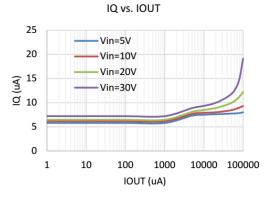


Temperature (°C)

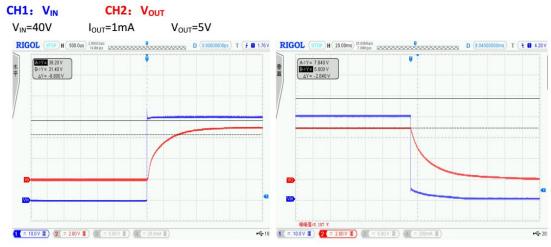
Output current (mA)

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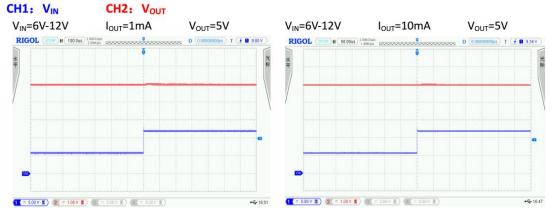
# TX75XXH series 150mA Low Power LDO



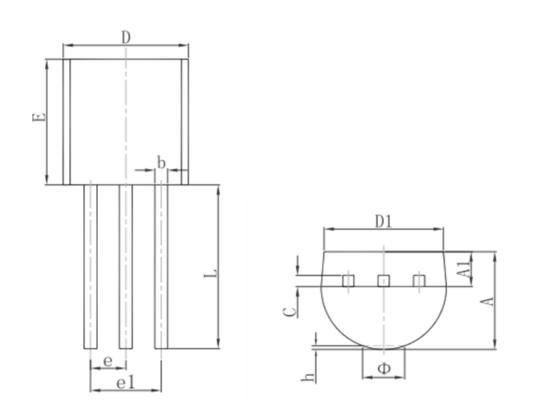
### Power ON/OFF



### Line Transient

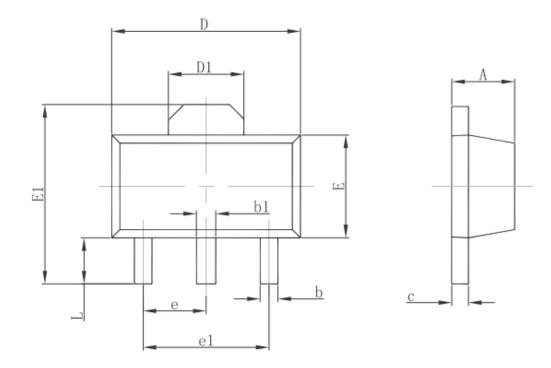


## Package Information 3-pin TO92 Outline Dimensions



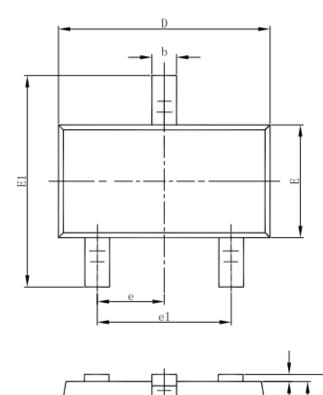
Symbol	Dimensions	Dimensions In Millimeters		s In Inches
Symbol	Min.	Max.	Min.	Max.
Α	3.300	3.700	0.130	0.146
A1	1.100	1.400	0.043	0.055
b	0.380	0.550	0.015	0.022
С	0.360	0.510	0.014	0.020
D	4.300	4.700	0.169	0.185
D1	3.430		0.135	
E	4.300	4.700	0.169	0.185
e	1.270	TYP.	0.050	TYP.
e1	2.440	2.640	0.096	0.104
L	14.100	14.500	0.555	0.571
Φ		1.600		0.063
h	0.000	0.380	0.000	0.015

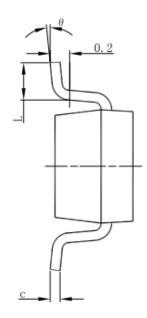
## 3-pin SOT89 Outline Dimensions



Symbol	Dimensions In Millimeters		Dimension	s In Inches
Symbol	Min.	Max.	Min.	Max.
Α	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.400	0.580	0.016	0.023
С	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550	REF.	0.061 REF.	
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
е	1.500 TYP.		0.060 TYP.	
e1	3.000 TYP.		0.118	3 TYP.
L	0.900	1.200	0.035	0.047

## 3-pin SOT23-3 Outline Dimensions

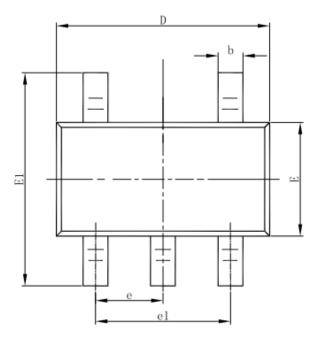


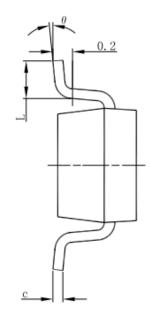


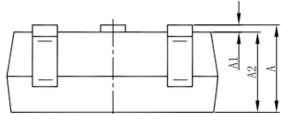
Symbol	Dimensions I	n Millimeters	Dimensions	In Inches
Symbol	Min	Max	Min	Max
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
е	0.950	(BSC)	0.037(	BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

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## **SOT23-5** Outline Dimensions



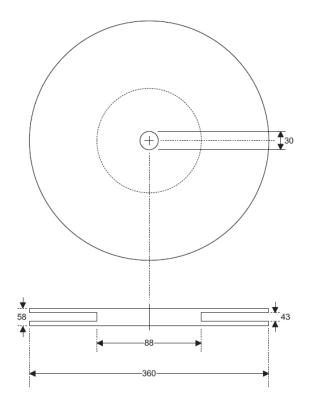


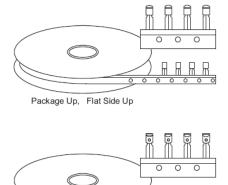


Sumb a l	Dimensions In	Millimeters	Dimensions	In Inches
Symbol	Min	Max	Min	Max
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
е	0.950(	BSC)	0.037(	BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	<mark>8°</mark>

## Product Tape and Reel Specifications

3-pin TO92 Reel Dimensions (Unit: mm)



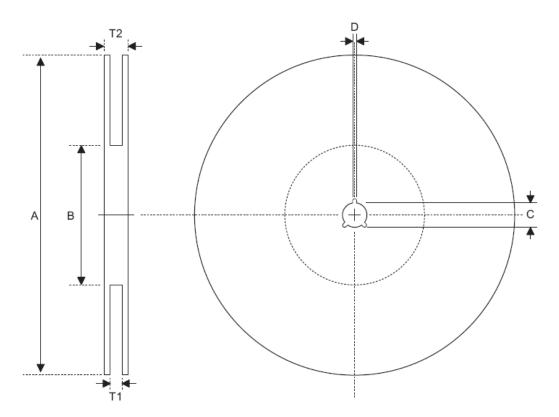


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Package Up, Flat Side Down

## **Reel Dimensions**



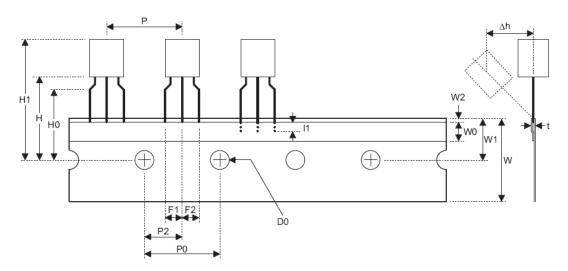
#### SOT89

Symbol	Description	Dimensions in mm
А	Reel Outer Diameter	180.0±1.0
В	Reel Inner Diameter	62.0±1.5
С	Spindle Hole Diameter	12.75 <sup>+0.15/-0.00</sup>
D	Key Slit Width	1.90±0.15
T1	Space Between Flange	12.4 <sup>+0.2/-0.00</sup>
T2	Reel Thickness	17.0 <sup>+0.0/-0.4</sup>

#### SOT23-5

Symbol	Description	Dimensions in mm
А	Reel Outer Diameter	178.0±1.0
В	Reel Inner Diameter	62.0±1.0
С	Spindle Hole Diameter	13.0±0.2
D	Key Slit Width	2.50±0.25
T1	Space Between Flange	8.4 <sup>+1.5/-0.0</sup>
T2	Reel Thickness	11.4 <sup>+1.5/-0.0</sup>

## **Carrier Tape Dimensions**



TO92

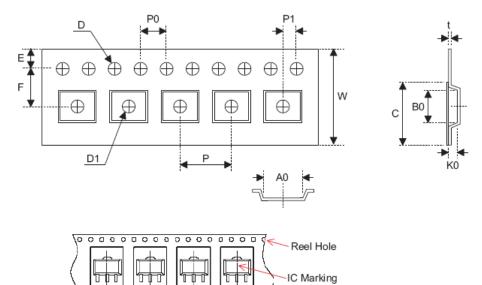
Symbol	Description	Dimensions in mm
11	Taped Lead Length	(2.5)
Р	Component Pitch	12.7±1.0
P <sub>0</sub>	Perforation Pitch	12.7±0.3
P <sub>2</sub>	Component to Perforation (Length Direction)	6.35±0.40
F <sub>1</sub>	Lead Spread	2.5 <sup>+0.4/-0.1</sup>
F <sub>2</sub>	Lead Spread	2.5 <sup>+0.4/-0.1</sup>
Δh	Component Alignment	0.0±0.1
W	Carrier Tape Width	18.0 <sup>+1.0/-0.5</sup>
W <sub>0</sub>	Hold-down Tape Width	6.0±0.5
W <sub>1</sub>	Perforation Position	9.0±0.5
W <sub>2</sub>	Hold-down Tape Position	(0.5)
H <sub>0</sub>	Lead Clinch Height	16.0±0.5
H <sub>1</sub>	Component Height	Less than 24.7
D <sub>0</sub>	Perforation Diameter	4.0±0.2
t	Taped Lead Thickness	0.7±0.2
Н	Component Base Height	19.0±0.5

Note: Thickness less than 0.38\_0.05mm~0.5mm

P0 Accumulated pitch tolerance: \_1mm/20pitches.

() Bracketed figures are for consultation only

## **Carrier Tape Dimensions**



#### SOT89

Symbol	Description	Dimensions in mm
W	Carrier Tape Width	12.0 <sup>+0.3/-0.1</sup>
Р	Cavity Pitch	8.0±0.1
E	Perforation Position	1.75±0.10
F	Cavity to Perforation (Width Direction)	5.50±0.05
D	Perforation Diameter	1.5 <sup>+0.1/-0.0</sup>
D1	Cavity Hole Diameter	1.5 <sup>+0.1/-0.0</sup>
P0	Perforation Pitch	4.0±0.1
P1	Cavity to Perforation (Length Direction)	2.0±0.1
A0	Cavity Length	4.8±0.1
B0	Cavity Width	4.5±0.1
K0	Cavity Depth	1.8±0.1
t	Carrier Tape Thickness	0.300±0.013
С	Cover Tape Width	9.3±0.1

#### SOT23-5

Symbol	Description	Dimensions in mm
W	Carrier Tape Width	8.0±0.3
Р	Cavity Pitch	4.0±0.1
E	Perforation Position	1.75±0.10
F	Cavity to Perforation (Width Direction)	3.50±0.05
D	Perforation Diameter	1.5 <sup>+0.1/-0.0</sup>
D1	Cavity Hole Diameter	1.5 <sup>+0.1/-0.0</sup>
P0	Perforation Pitch	4.0±0.1
P1	Cavity to Perforation (Length Direction)	2.00±0.05
A0	Cavity Length	3.15±0.10
B0	Cavity Width	3.2±0.1
K0	Cavity Depth	1.4±0.1
t	Carrier Tape Thickness	0.20±0.03
С	Cover Tape Width	5.3±0.1

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